


APPLICATION DATA SHEET

Electronic Version v14

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Title of Invention	[POLYSILICON THIN FILM TRANSISTOR AND METHOD OF FORMING THE SAME]		
Application Type :		regular, utility	
Attorney Docket Number :		9893-US-PA	
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Customer Number:	31561		
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as our attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith.